

#### **GENERAL DESCRIPTION**

DP2360 combines a dedicated high performance current mode PWM controller with a high voltage power MOSFET. It is optimized for low standby power and cost effective off-line flyback converter applications in sub 27W range.

In DP2360, PWM switching frequency with shuffling is fixed to 65KHz and is trimmed to tight range. The IC has built-in green and burst mode control for light and zero loadings, which can achieve less than 75mW standby.

DP2360 offers complete protections coverage with automatic self-recovery feature including Cycle-by-Cycle current limiting (OCP), over load protection (OLP), On-chip Thermal Shutdown (OTP), VDD over voltage protection (VDD OVP) and VDD under voltage lockout (UVLO), etc. Excellent EMI performance is achieved with frequency shuffling and soft totem pole gate drive The tone energy at below 20KHz is minimized in the design and audio noise is eliminated during operation.

DP2360 is offered in DIP package.

#### **FEATURES**

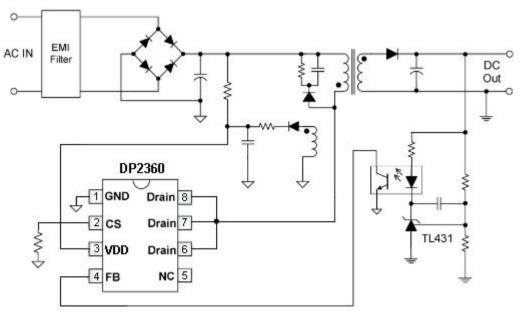
- Less than 75mW Standby Power at Universal Input
- Built-in 650V Power MOSFET
- Power on Soft Start Reducing MOSFET Vds Stress
- Frequency Shuffling for EMI
- Fixed 65KHz Switching Frequency
- Internal Synchronized Slope Compensation
- Low VDD Startup Current and Low Operating Current
- Built-in Leading Edge Blanking
- On-chip Thermal Shutdown (OTP) with Auto-recovery
- Soft Gate Driver for Good EMI Performance
- Over Load Protection
- Cycle-by-Cycle Current Limiting
- VDD Under Voltage Lockout with Hysteresis (UVLO)
- VDD OVP & Clamp

#### **APPLICATIONS**

Offline AC/DC flyback converter for

- AC/DC Adapter
- Set-Top Box Power
- PDA Power Supplies
- Open-frame SMPS
- VCR, SVR, STB, DVD Player SMPS

#### TYPICAL APPLICATION



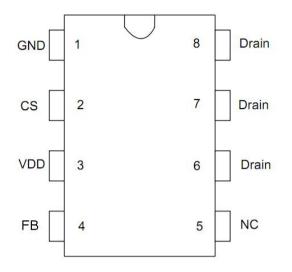


#### High Performance Current Mode PWM Power Switch

#### **GENERAL INFORMATION**

## **Pin Configuration**

The pin map of DIP8 package is shown as below.



**Ordering Information** 

Part Number	Description	
DP2360	DIP8, Pb-free	50Pcs/Tube

### **Package Dissipation Rating**

Package	RθJA (℃/W)		
DIP8	75		

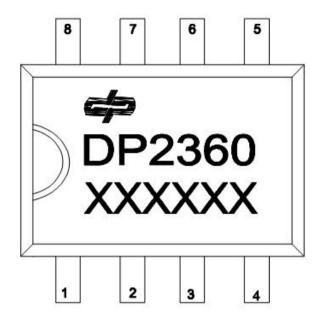
**Absolute Maximum Ratings** 

Absolute Maximum Ratings						
Parameter	Value					
Drain Voltage (off state)	-0.3 to 650V					
VDD Zener Clamp Voltage	$V_{DD\_Clamp}$					
VDD Clamp Continuous Current	10 mA					
CS Input Voltage	-0.3 to 7V					
FB Input Voltage	-0.3 to 7V					
Maximum Operating Junction Temperature T <sub>J</sub>	150 °C					
Min/Max Storage Temperature T <sub>stg</sub>	-55 to 150 °C					
Lead Temperature (Soldering, 10secs)	260 °C					

**Note:** Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.



# **Marking Information**



## Description:

DP2360 for product name;

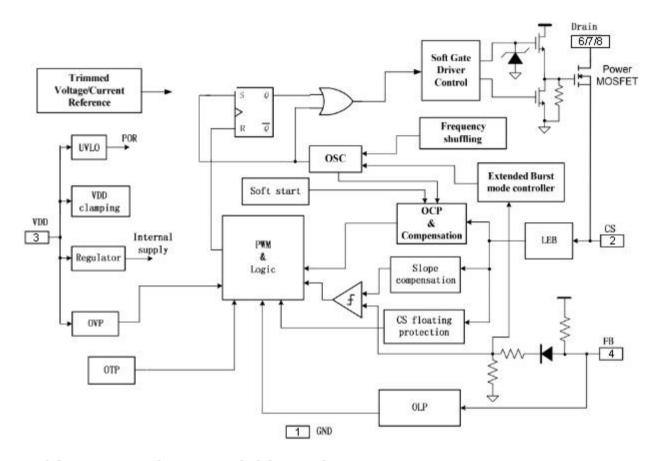
XXXXX the first X represents the last year,2016 is 6; The second X represents the month, in A -L 12 letters; The third and fourth X On behalf of the date, 01-31 said; The last two X represents the wafer batch code.

## **TERMINAL ASSIGNMENTS**

Pin Num	Pin Name	I/O	Description		
1	GND	Р	Ground.		
2	CS	1	Current sense input.		
3	VDD	Р	Power supply.		
4	FB	I	Feedback pin. The loop regulation is achieved by connecting a photo-coupler to this pin. PWM duty cycle is determined by this pin voltage and the current sense signal at Pin 4.		
5	NC	-	No connect.		
6/7/8	Drain	0	The Power MOSFET Drain		



## **BLOCK DIAGRAM**



## RECOMMENDED OPERATING CONDITION

Symbol	Parameter	Min	Max	Unit
VDD	VDD Supply Voltage	11	26	V
T <sub>A</sub>	Operating Ambient Temperature	-40	85	°C





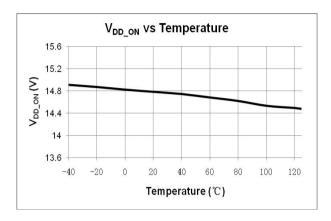
## **ELECTRICAL CHARACTERISTICS**

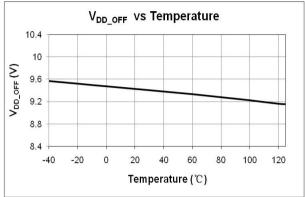
(T<sub>A</sub> = 25°C, VDD=18V if not otherwise noted)

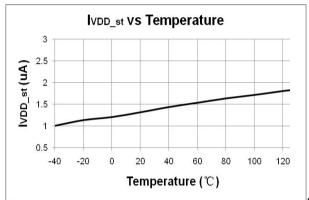
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
<b>Supply Voltage</b>	e Section (VDD Pin)					
I <sub>VDD_st</sub>	Start-up current into VDD pin			0	15	uA
I <sub>VDD_Op</sub>	Operation Current	V <sub>FB</sub> =3V		1.2	2	mA
I <sub>VDD_standby</sub>	Standby Current			0.7	1.3	mA
$V_{DD\_ON}$	VDD Under Voltage Lockout Exit		19.2	20.8	22.4	٧
$V_{DD\_OFF}$	VDD Under Voltage Lockout Enter		8.2	9.2	10.2	V
$V_{\text{DD\_OVP}}$	VDD OVP Threshold		29	31	33	V
$V_{DD\_Clamp}$	VDD Zener Clamp Voltage	$I(V_{DD}) = 7 \text{ mA}$	33.5	35.5	37.5	V
Feedback Inpu	t Section (FB Pin)					
V <sub>FB_Open</sub>	FB Open Voltage		4.5	5.4	6	V
I <sub>FB_Short</sub>	FB Short Circuit Current	Short FB Pin to GND, Measure Current		0.3		mA
Acs	PWM Gain	Δ V <sub>FB</sub> / Δ V <sub>CS</sub>		2.0		V/V
V <sub>skip</sub>	FB Under Voltage PWM Clock is OFF			1.0		V
V <sub>TH_OLP</sub>	Power Limiting FB Threshold Voltage			3.6		V
T <sub>D_OLP</sub>	Power Limiting Debounce Time			43		ms
Z <sub>FB</sub> IN	FB Input Impedance			20		Kohm
	Input Section (CS Pin)					
T <sub>LEB</sub>	CS Input Leading Edge Blanking Time			250		ns
V <sub>cs(max)</sub>	Current limiting threshold		0.97	1.0	1.03	V
T <sub>D_OCP</sub>	Over Current Detection and Control Delay			70		ns
Oscillator Sect				•		•
Fosc	Normal Oscillation Frequency		60	65	70	KHz
△ F(shuffle) /F <sub>OSC</sub>	Frequency Shuffling Range		-4		4	%
D <sub>MAX</sub>	Maximum Switching Duty Cycle			66.7		%
F <sub>Bust</sub>	Burst Mode Base Frequency			22		KHz
Over temperature Protection						·
T <sub>SD</sub>	Thermal Shutdown			165		° C
T <sub>RC</sub>	Thermal Recovery			140		° C
Power MOSFET Section (Drain Pin)						
V <sub>BR</sub>	MOSFET Drain Source Breakdown Voltage		650			V
R <sub>dson</sub>	Static Drain-Source On Resistance			2.6	3.0	Ohm

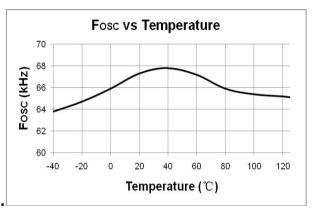


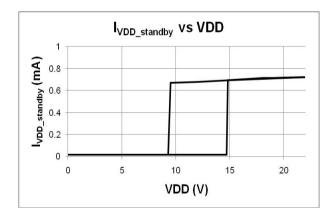
#### **CHARACTERIZATION PLOTS**

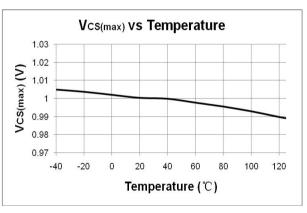
















#### **OPERATION DESCRIPTION**

DP2360 is a low power off-line SMPS Switcher optimized for off-line flyback converter applications in sub 27W power range. The IC can achieve less than 75mW standby power and helps the design easily to meet the international power conservation requirements.

#### Startup Current and Start up Control

Startup current of DP2360 is designed to be very low so that VDD could be charged up above UVLO threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet reliable startup in application.

#### Operating Current

The operating current of DP2360 is as low as 1mA. Good efficiency is achieved by the low operating current together with extended burst mode control schemes at No/light load conditions.

#### Soft Start

DP2360 features an internal 4ms (typical) soft start to soften the electrical stress occurring in the power supply during startup. It is activated during the power on sequence. As soon as VDD reaches UVLO(OFF), the peak current is gradually increased from nearly zero to the maximum level of 1V. Every restart up is followed by a soft start.

#### Oscillator with Frequency Shuffling

PWM switching frequency in DP2360 is fixed to 65KHz and is trimmed to tight range. To improve system EMI performance, DP2360 operates the system with 4% frequency shuffling around setting frequency.

#### Current Sensing and Leading Edge Blanking

Cycle-by-Cycle current limiting is offered in DP2360. The switch current is detected by a sense resistor into the CS pin. An internal leading edge blanking circuit is built in. During this blanking period (250ns, typical), the cycle-by-cycle current limiting comparator is disabled and cannot switch off the GATE driver.

## ynchronous Slope Compensation

In DP2360, the synchronous slope compensation circuit is integrated by adding voltage ramp onto the current sense input voltage for PWM generation. This greatly improves the close loop stability at CCM and

prevents the sub-harmonic oscillation and thus reduces the output ripple voltage.

#### Extended Burst Mode Operation

At zero load or light load condition, most of the power dissipation in a switching mode power supply is from switching loss on the MOSFET transistor, the core loss of the transformer and the loss on the snubber circuit. Reducing switching events leads to the reduction on the power loss and thus conserves the energy.

DP2360 self adjusts the switching mode according to the loading condition. At no load or light load condition, the FB input is below burst mode threshold level. Device enters Burst Mode control. The Gate drive output switches only when VDD voltage drops below a preset level and FB input is active to output an on state. Otherwise the gate drive remains at off state to minimize the switching loss thus reduce the standby power consumption to the greatest extension. The nature of high frequency switching also reduces the audio noise at any loading conditions.

#### Audio Noise Free Operation

DP2360 can provide audio noise free operation from full loading to zero loading.

#### Over Temperature Protection (OTP)

When the IC temperature is over  $165\,^{\circ}$ C, the IC shuts down. Only when the IC temperature drops to  $135\,^{\circ}$ C, IC will restart.

#### VDD OVP and Zener Clamp

When VDD voltage is higher than 28.5V (typical), the IC will stop switching. This will cause VDD fall down to be lower than VDD\_OFF (typical 9.4V) and then the system will restart up again. An internal 32V (typical) zener clamp is integrated to prevent the IC from damage.

#### Soft Gate Drive

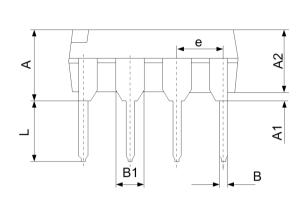
DP2360 has a soft totem-pole gate driver with optimized EMI performance. An internal 16V clamp is added for MOSFET gate protection at higher than expected VDD input. Too weak the gate drive strength results in higher conduction and switch loss of MOSFET while too strong gate drive output compromises the EMI.

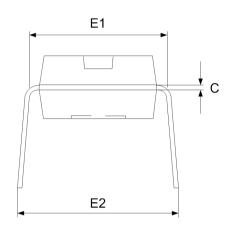
Good tradeoff is achieved through the built-in totem pole gate drive design with right output strength and dead time control. The low idle loss and good EMI system design is easier to achieve with this dedicated control scheme.

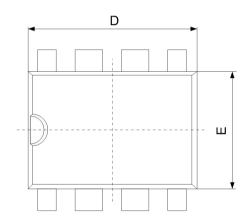


# **Package Dimension**

# DIP8







Cymhal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	3.710	5.334	0.146	0.210	
A1	0.381		0.015		
A2	3.175	3.600	0.125	0.142	
В	0.350	0.650	0.014	0.026	
B1	1.524 (	1.524 (BSC)		06 (BSC)	
С	0.200	0.360	0.008	0.014	
D	9.000	10.160	0.354	0.400	
E	6.200	6.600	0.244	0.260	
E1	7.320	7.920	0.288	0.312	
е	2.540 (BSC)		0.1 (BSC)		
L	2.921	3.810	0.115	0.150	
E2	8.200	9.525	0.323	0.375	